

Schottky Diodes



- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 ℃

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

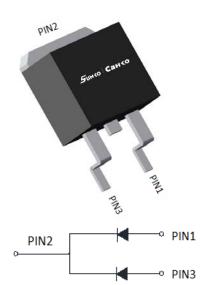
Mechanical Data

• Package: TO-263

Molding compound meets UL 94 V-0 flammability

 Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

Polarity: As marked



■Maximum Ratings (Tj=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRB40200CT
Device marking code			MBRB40200CT
Repetitive Peak Reverse Voltage	V_{RRM}	V	200
Average Rectified Output Current @60Hz sine wave, R-load, Tc (FIG.1)	Io	А	40
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Tj=25°C		А	300
Surge(Non-repetitive)Forward Current @1ms, square wave, 1 time, Tj=25°C	I _{FSM}		600
Current Squared Time @1ms≤t≤8.3ms Tj=25˚ℂ,	l²t	A ² s	373
Storage Temperature	T _{stg}	°C	-55 ~ + 175
Junction Temperature	Tj	$^{\circ}$	-55 ~ +175

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

TELECTRICAL CHARGES (18 20 CHICGS CHOMICS SPECIFICA)				
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRB40200CT
Maximum instantaneous forward voltage drop per diode	VF	٧	IF=20A, Tj=25℃	0.90
Maximum DC reverse current at rated DC blocking voltage per diode @ VRM=VRRM	IRRM mA		VRM=VRRM Tj=25℃	0.1
		mA	VRM=VRRM Tj=125℃	20

Note1:Pulse test:300uS pulse widh,1% duty cycle

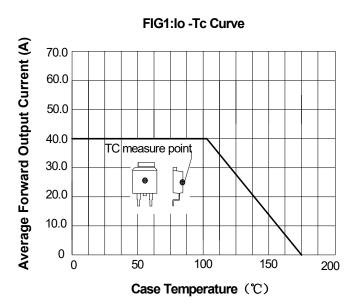
Note2:Pulse test:pulse widh 40mS



■Thermal Characteristics $(T_j=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

	PARAMETER	SYMBOL	UNIT	MBRB40200CT
Thermal Resistance	Between junction and ambient	R _{0J-A}	°C/W	50.0
	Between junction and case	$R_{ heta J-C}$	°C/W	2.0

■Characteristics (Typical)



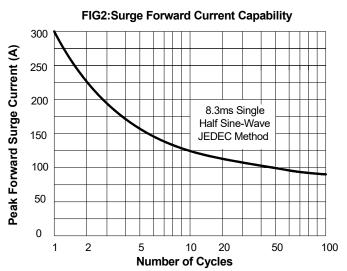
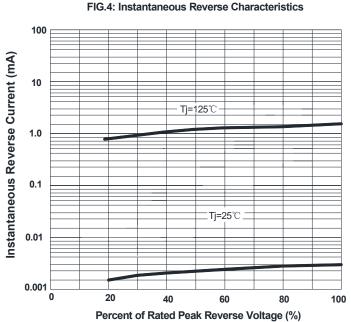
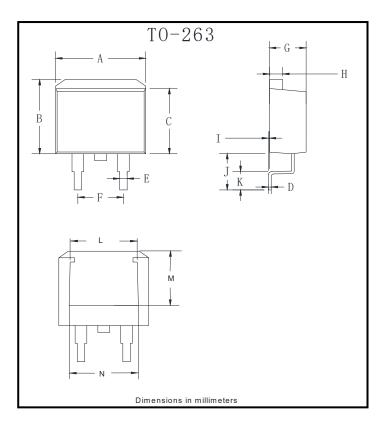


FIG3: Forward Voltage 50 Instantaneous Forward Current (A) 20 10 5.0 2.0 0.5 0.2 Tj=25°C 0.1 0.2 0.3 0.5 0.6 0.7 0.8 0.9 1.0 Instantaneous Forward Voltage (V)



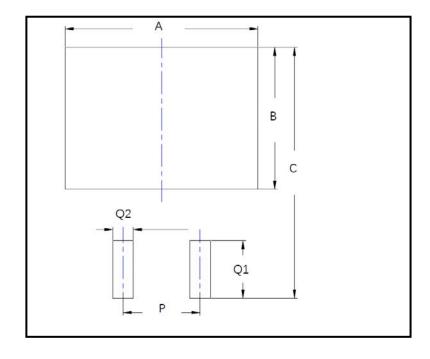


■Outline Dimensions



TO-263			
Dim	Min	Max	
Α	9.5	11.5	
В	9.7	10.5	
С	8.4	9.0	
D	0.28	0.64	
Е	0.68	0.94	
F	4.55	5.6	
G	4.04	5.10	
Н	1.14	1.4	
I	0	0.2	
J	4.9	6.05	
K	1.79	2.79	
L	7.3	7.9	
М	6.2	6.8	
N	7.6	8.2	

■Suggested Pad Layout



Dim	Millimeters	
Α	12.7	
В	9.4	
С	16.6	
Р	5.08	
Q1	3.8	
Q2	1.35	



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